

CZECH PARTICIPATION AT
FACILITY FOR ANTIPROTON AND ION RESEARCH (FAIR)
AND NUCLOTRON-BASED ION COLLIDER FACILITY (NICA)



Tests of radiation hardness of SiPMs and scintillators

*Vasily Mikhaylov on behalf of team of
Nuclear Physics Institute of the Czech Academy of Sciences*

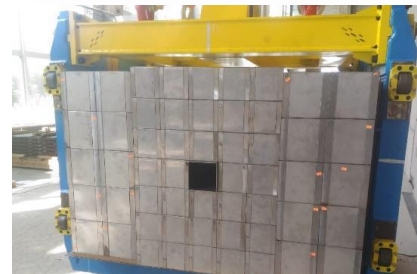
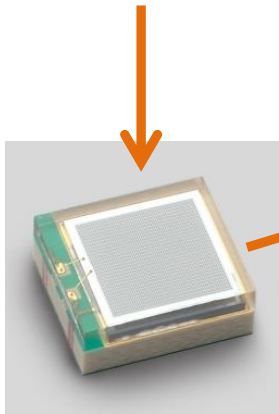
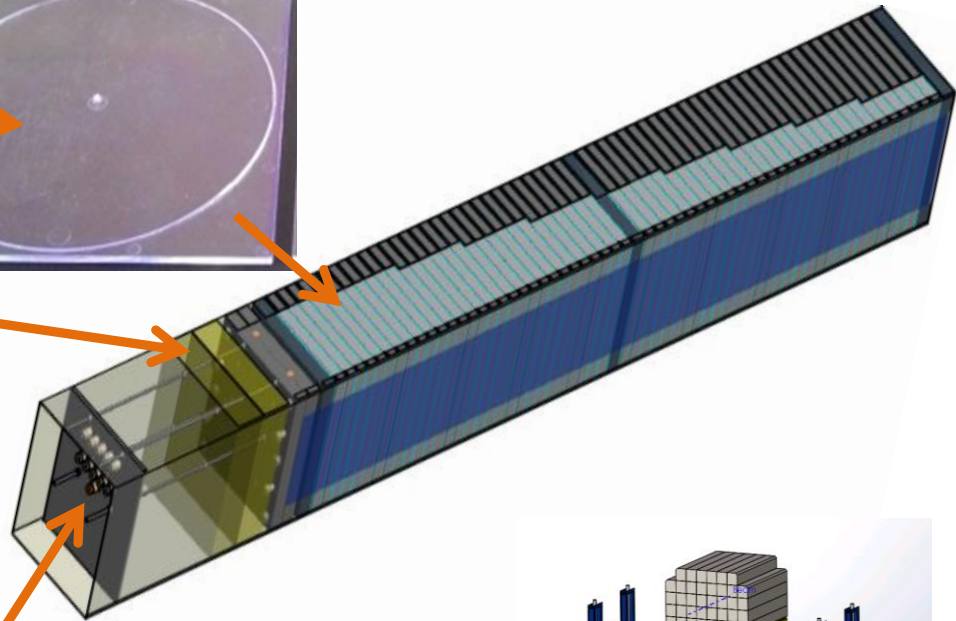
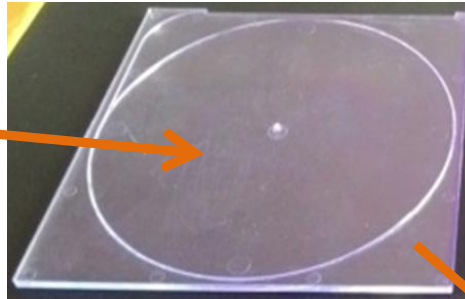


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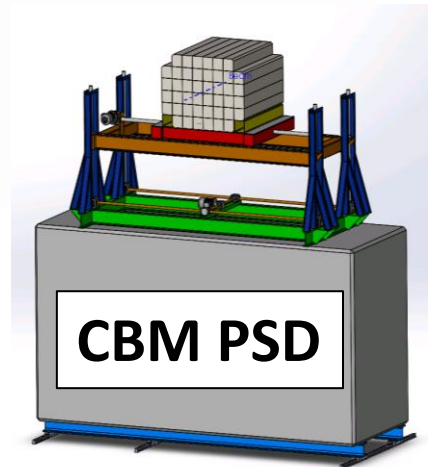


Calorimeter radiation hardness

- Proton irradiation study of polystyrene **scintillators**.
- Simulation of polyethylene **neutron shielding**.
- Neutron irradiation study of **Silicon Photomultipliers**.

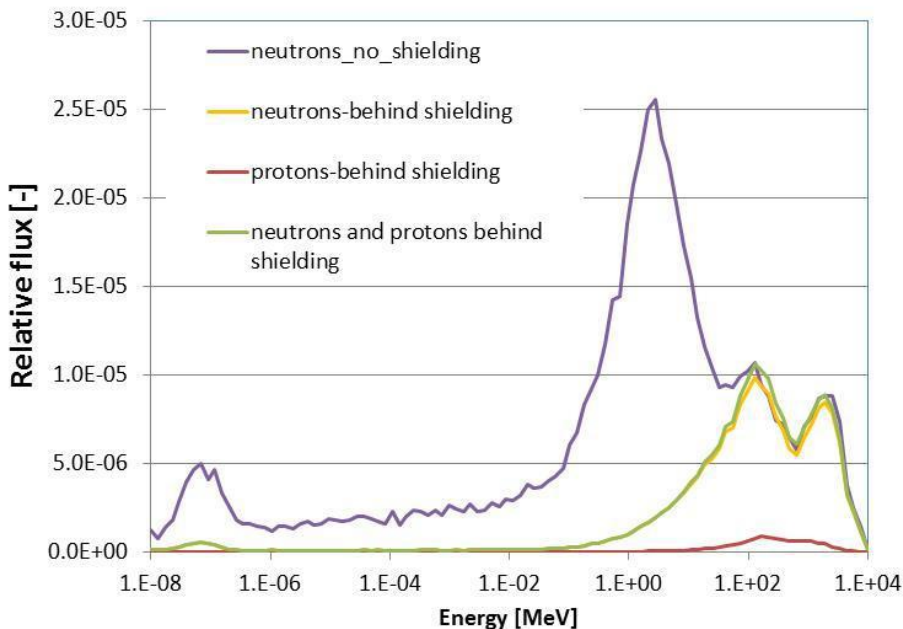


BM@N FHCAL

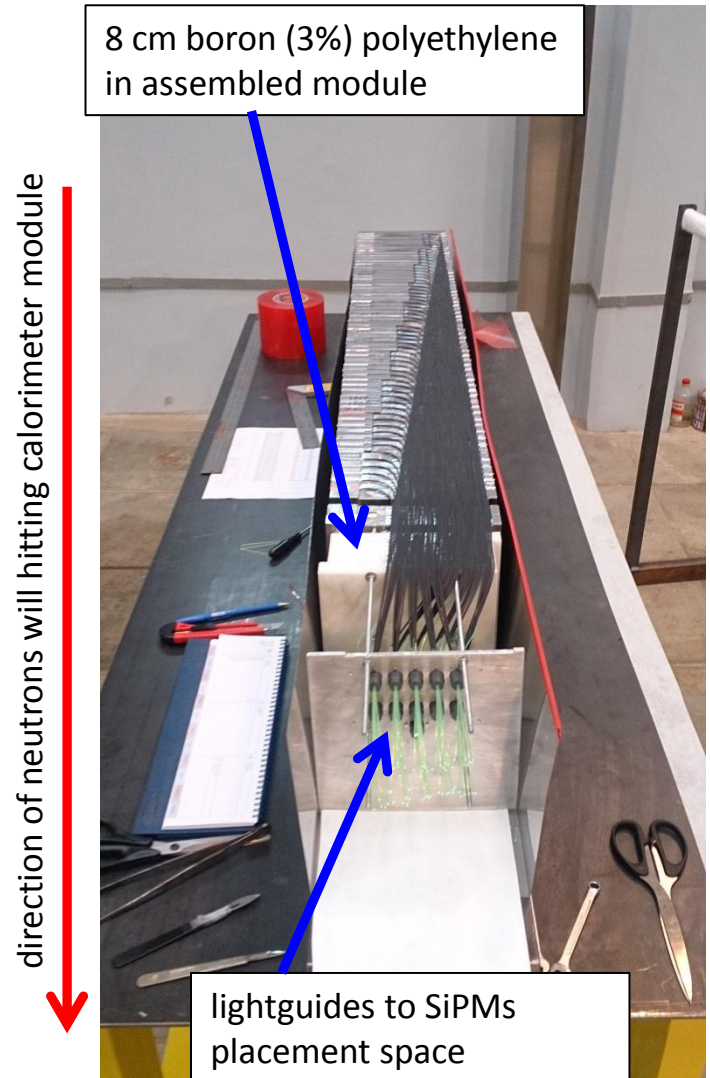


Neutron shielding simulation

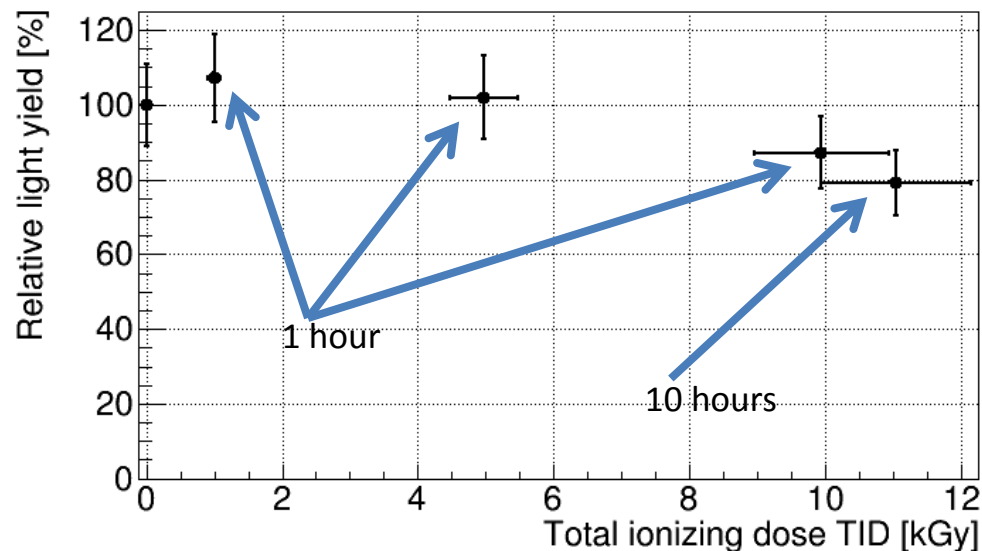
- We reduced the neutron flux by 50-70% adding borated polyethylene between the calorimeter module lead/scintillator blocks and SiPMs.
- Low energetic neutrons are shielded the best, so we reduce the neutrons captured in SiPM by silicon and dopants, especially ^{10}B dopant having huge n cross-section.



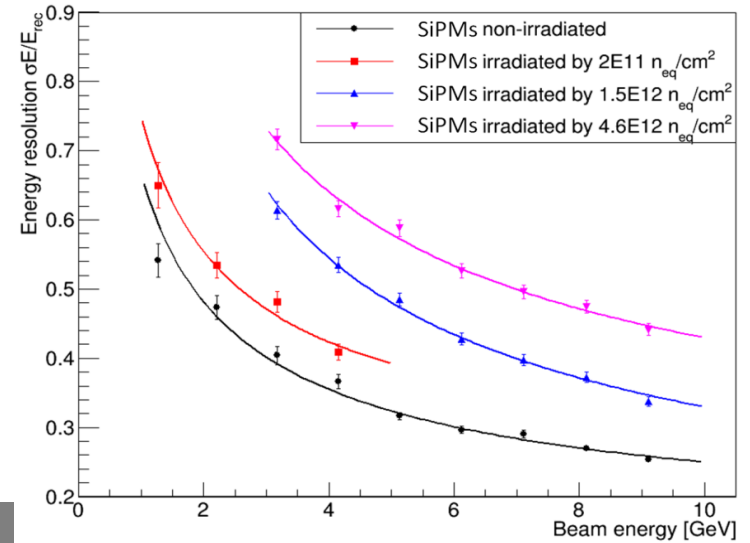
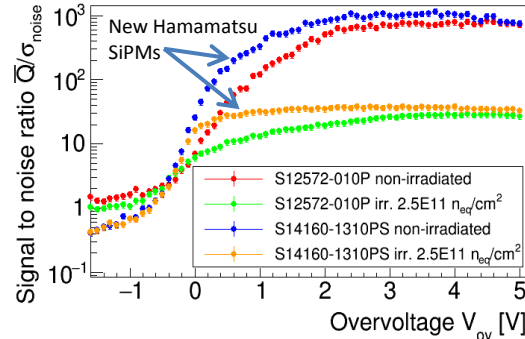
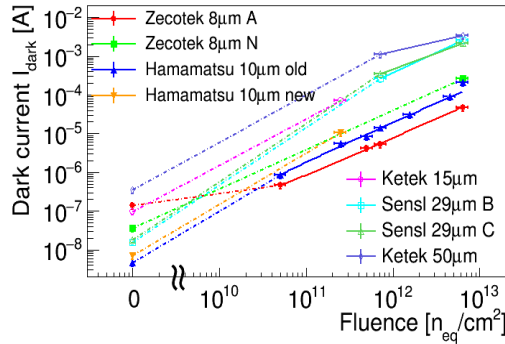
Contribution of O. Svoboda



Irradiation tests of scintillators



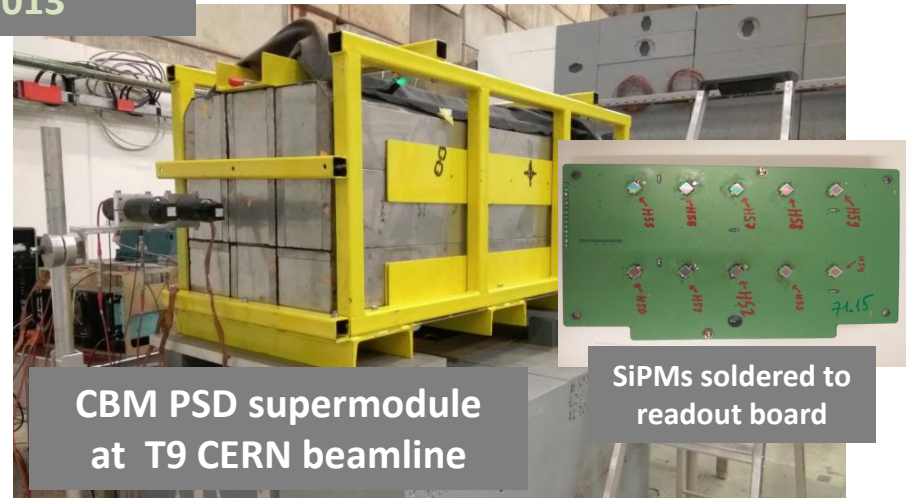
Irradiation tests of Silicon Photomultipliers



Screenshot of R.D.S.D. Statics Software V002 small. The main window shows a graph of Capacitance [pF] versus Voltage [V]. The y-axis ranges from 200 to 1201 pF, and the x-axis ranges from 0.00 to 66.78 V. The graph shows a sharp decrease in capacitance from approximately 1100 pF at 0 V to about 250 pF at 5 V, then it levels off. The software interface includes various control panels for voltage, frequency, and data logging.

Many tests conducted since 2013

Software for SiPM laboratory tests



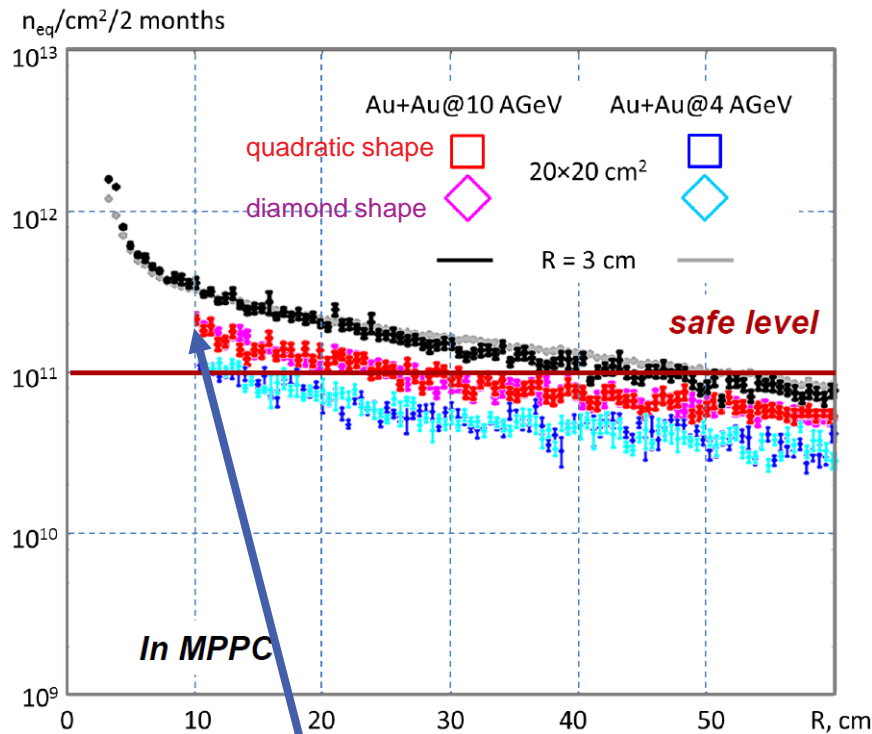
CBM PSD supermodule at T9 CERN beamline

SiPMs soldered to readout board

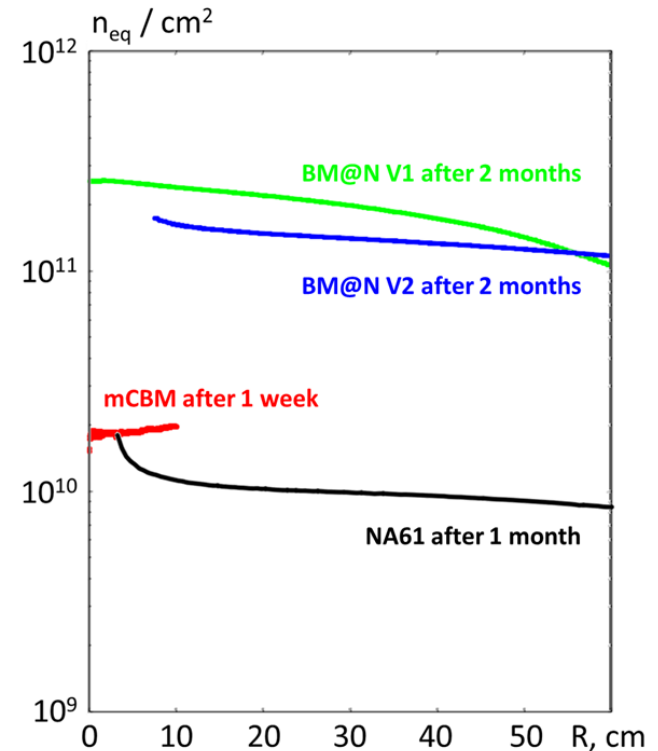
backup

Calorimeter radiation conditions

Enlarged beam hole 6x6 cm² -> 20x20 cm² significantly reduces the radiation damage



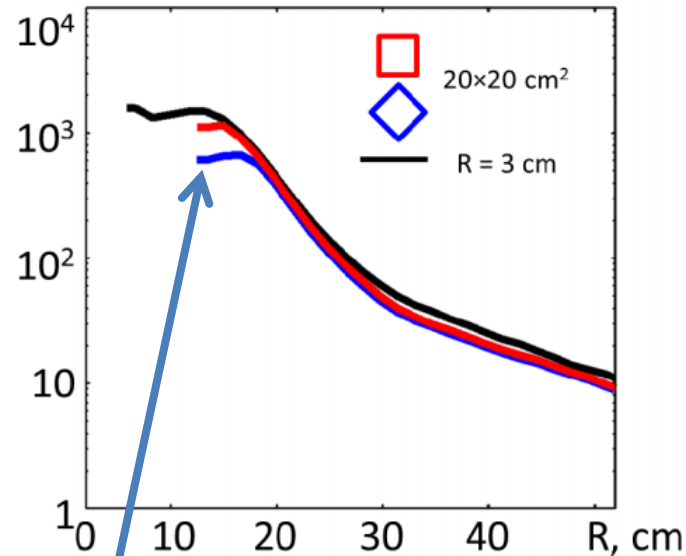
up to 2×10^{11} neutrons_{eq}/cm² for SiPMs located 10 cm close to the beam center



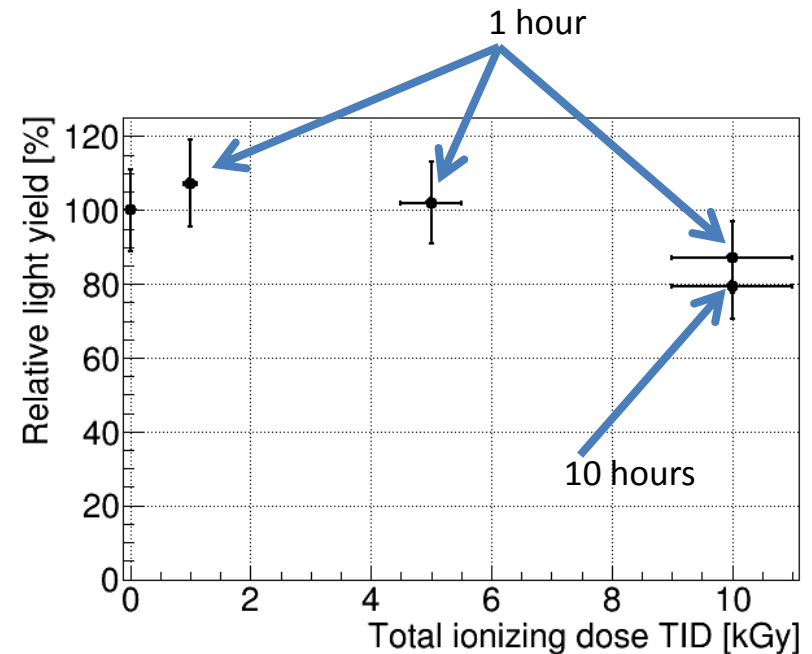
Simulation by A. Senger

Scintillator irradiation test

Gy after 2 months



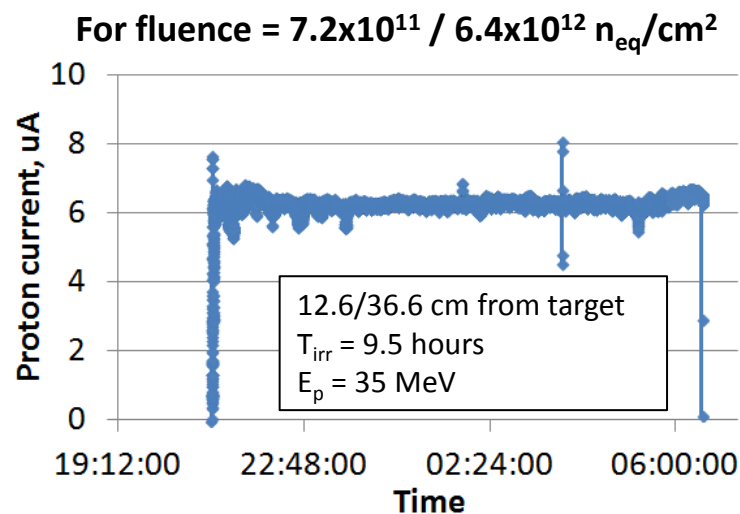
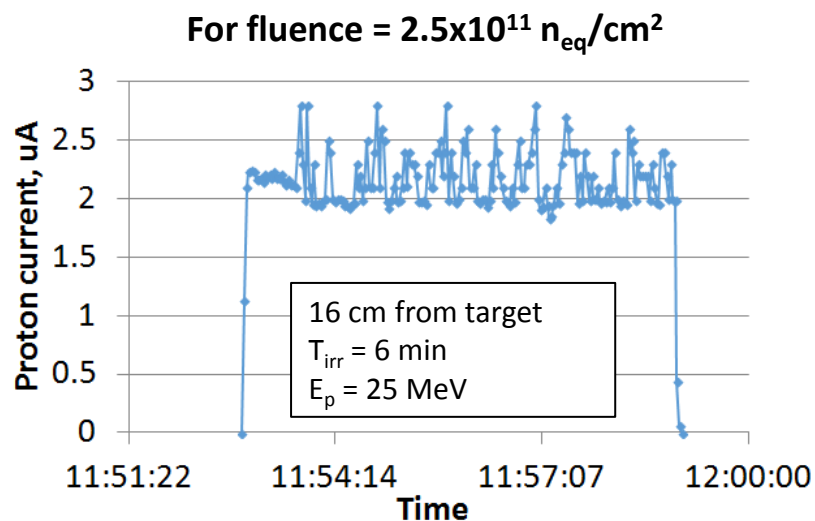
Up to 1 kGy for 1 year of experiment run



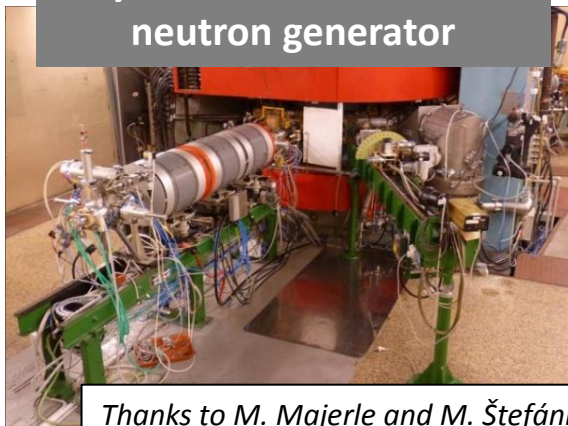
- Scintillators were irradiated at NPI cyclotron by 1, 5, 10 kGy during 1 – 10 hours
- Light yield did not decrease up to 5 kGy. After 10 kGy it decreased by up to 20 %

Work was done by V. Kushpil, V. Mikhaylov, A. Ivashkin and N. Karpushkin

Neutron irradiation experiments



Cyclotron U-120M with
neutron generator

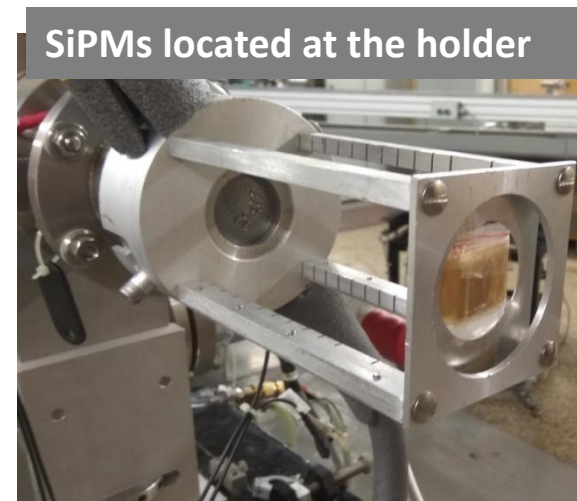


Thanks to M. Majerle and M. Štefánik

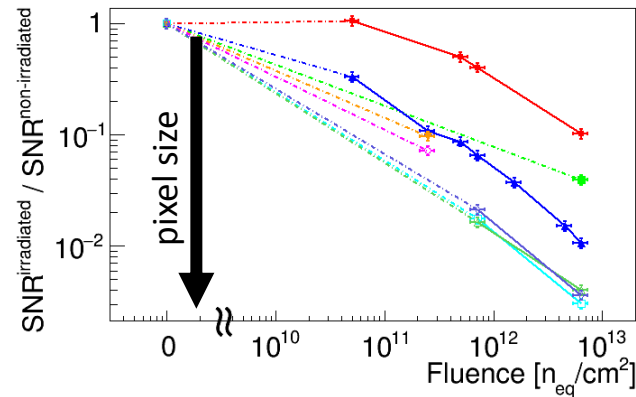
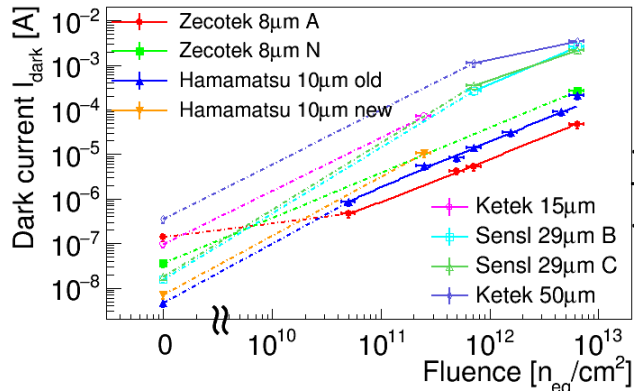
SiPMs and Au foil
prepared for irradiation



SiPMs located at the holder



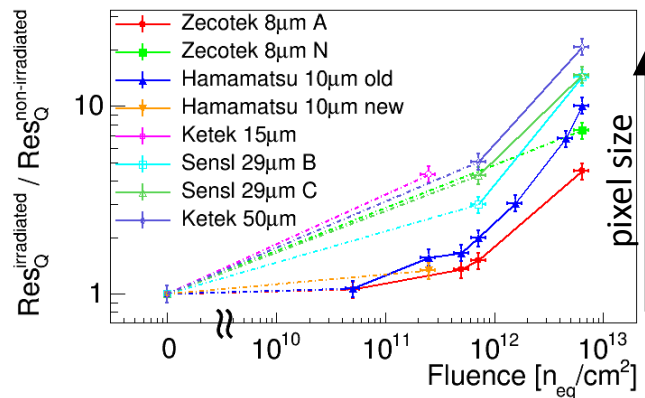
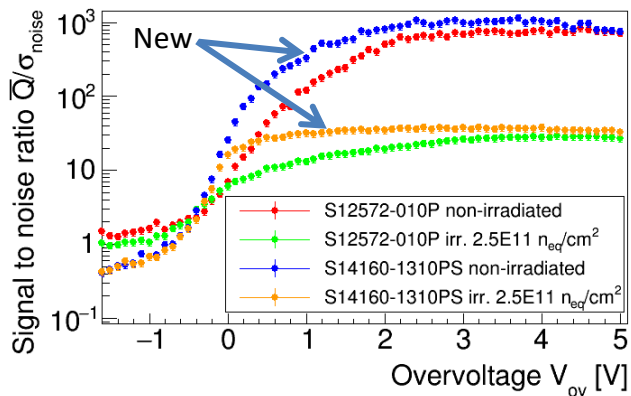
SiPM performance: dark current and response to LED



Linear dependence of dark current on fluence was observed.

SiPM signal response was measured during illumination with 10 ns short pulses from 400 nm LED.

Pulse height was chosen such that signal was detectable by all the SiPMs (very high).



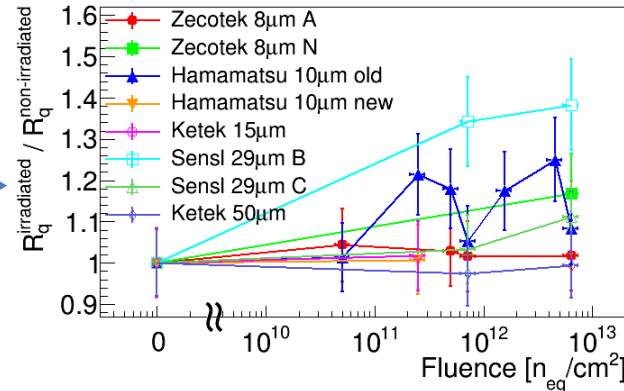
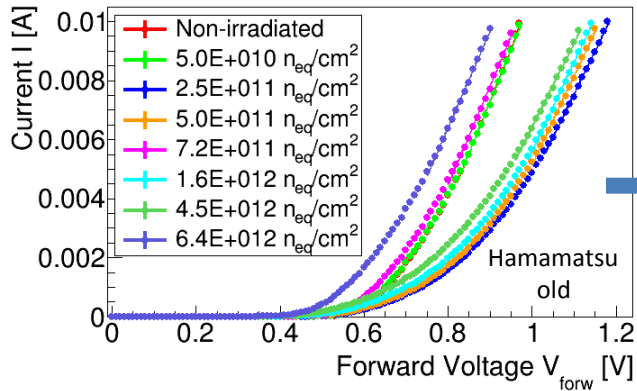
Signal to noise ratio = $\int_{signal} / \sigma_{signal}$
Resolution = $\sigma_{signal} / \int_{signal}$

Overvoltage is 1 V for graphs with fluence dependence.

Zecotek SiPMs cannot withstand rates > 10 kHz – not suitable for CBM.

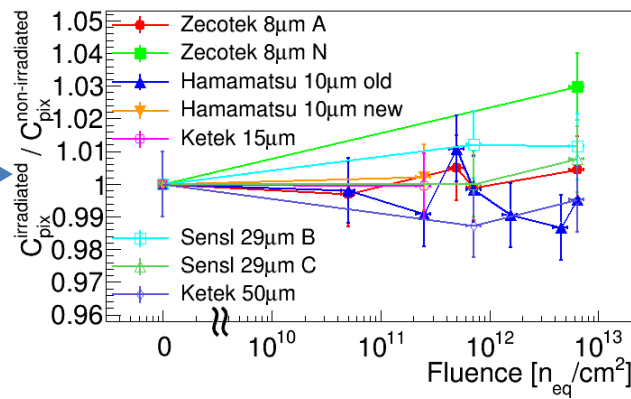
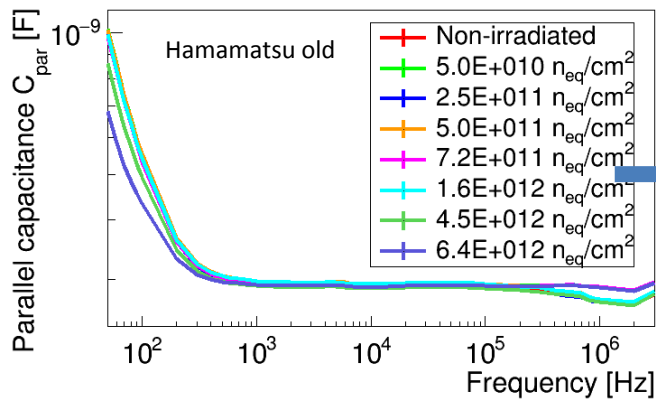
- Hamamatsu SiPMs are the best, probably due to very small pixels
- New version performs slightly better

SiPM performance: quenching resistance and pixel capacitance



At higher range of forward voltage
 $R_q \approx N_{pix} / (dI_{dark} / dV_{forw})$

At intermediate frequency ~ 10 kHz
 and around bias voltage
 $C_{pix} \approx C_{par} / N_{pix}$



➤ Quenching resistance and pixel capacitance did not change significantly